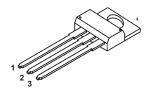
## **Bipolar Transistor**

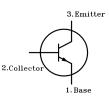


**RoHS** 

Compliant







## **Description:**

A Silicon NPN transistor in a TO-220 type package designed for high-voltage, high-speed power switching inductive circuits where fall time is critical. This device is particularly suited for 115V and 220V switch-mode applications such as switching regulators, inverters, motor controls, solenoid/relay drivers and deflection circuits

#### **Maximum Ratings:**

Characteristic	Symbol	Rating	Unit		
Collector-Emitter Voltage	V <sub>CEO(sus)</sub>	350	V		
Collector-Base Voltage	V <sub>CBO</sub>	6	V		
Collector Current - Continuous - Peak	Ι <sub>c</sub>	5 10	•		
Base Current - Continuous - Peak	I <sub>B</sub>	2 12	A		
Total Power Dissipation (T <sub>C</sub> = +25°C), Derate Above 25°C	P <sub>D</sub>	80 640	W mW/°C		
Operating Junction Temperature	Τ <sub>J</sub>	-65 to +150	°C		
Storage Temperature Range	T <sub>stg</sub>	-05 10 + 150	0		
Thermal Resistance, Junction-to-case	R <sub>thjc</sub>	1.56	°C/W		
Lead Temperature (During Soldering, 1/8" from case, 5 sec)	TL	+275	°C		

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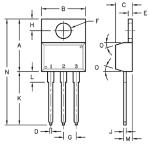
# **Bipolar Transistor**



Parameter	Symbol	Test Conditions	Min.	Тур	Max.	Unit
OFF Characteristics (Note 1)						
Collector - Emitter Sustaining Voltage	V <sub>CEO(sus)</sub>	I <sub>C</sub> = 25mA, I <sub>B</sub> = 0	350	-	-	V
Collector Cutoff Current	I <sub>CEV</sub>	V <sub>CEV</sub> = 450V, V <sub>BE(off)</sub> = 1.5V	-	-	1	mA
		$V_{CEV}$ = 225V, $V_{BE(off)}$ = 1.5V T <sub>C</sub> = 100°	-	-	10	mA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> = 6V, I <sub>C</sub> = 0	-	-	1	mA
ON Characteristics (Note 1)						
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> - 10V, I <sub>C</sub> = 2.5A	10	-	75	
		V <sub>CE</sub> - 10V, I <sub>C</sub> = 5A	3	-	-	
Collector - Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = 2.5A, I <sub>B</sub> = .5A	-	-	1.5	V
		I <sub>C</sub> = 5A, I <sub>B</sub> = 2A	-	-	5	V
Deep Emitter Seturation Voltage	N	I <sub>C</sub> = 2.5A, I <sub>B</sub> = 0.5A	-	-	1.5	V
Base - Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> = 5A, I <sub>B</sub> = 2A	-	-	2.5	V
Dynamic Characteristics						
					1	

Switching Characteristics (Resistive Load)								
Output Capacitance	C <sub>ob</sub>	$V_{CB}$ - 10V, $I_{E}$ = 0, f = 0.1MHz	-	150	-	pF		
Current Gain - Bandwidth Product	f <sub>T</sub>	$V_{CE}$ - 10V, I <sub>C</sub> = 250mA, f = 1MHz	5	-	-	MHz		

Note 1 : Pulse test : -Pulse width = 5ms, duty cycle </= 10%



Pin Configuration:

- 1. Base
- 2. Collector
- 3. Emitter
- 4. Collector

Dim.	A	В	С	D	E	F	G	н	J	к	L	М	N	0
Min.	14.42	9.63	3.56	-	1.15	3.75	2.29	2.54	-	12.7	2.8	2.03	-	70
Max.	16.51	10.67	4.83	0.9	1.4	3.88	2.79	3.43	0.56	14.73	4.07	2.92	31.24	<b>'</b>

**Dimensions : Millimetres** 

### Part Number Table

Description	Part Number			
Transistor, NPN, 5A, 350V, TO-220	2N6499			

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